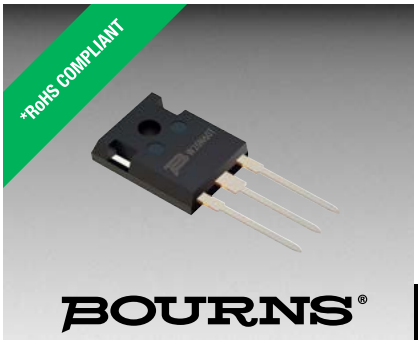


Features

- 600 V, 20 A, Low Collector-Emitter Saturation Voltage ($V_{CE(sat)}$)
- Novel trench-gate field-stop technology
- Optimized for conduction
- Low switching loss
- RoHS compliant*

Applications

- Switch-Mode Power Supplies (SMPS)
- Uninterruptible Power Sources (UPS)
- Power Factor Correction (PFC)
- Stepper motors

BIDW20N60T Insulated Gate Bipolar Transistor (IGBT)

General Information

The Bourns® Model BIDW20N60T IGBT device combines technology from a MOS gate and a bipolar transistor, resulting in an optimum component for high voltage and high current applications. This device uses advanced Trench-Gate Field-Stop technology providing greater control of dynamic characteristics while resulting in a lower conduction loss and fewer switching losses. In addition, this structure provides a positive temperature coefficient.

Additional Information

Click these links for more information:

PRODUCT SELECTOR | TECHNICAL LIBRARY | INVENTORY | SAMPLES | CONTACT

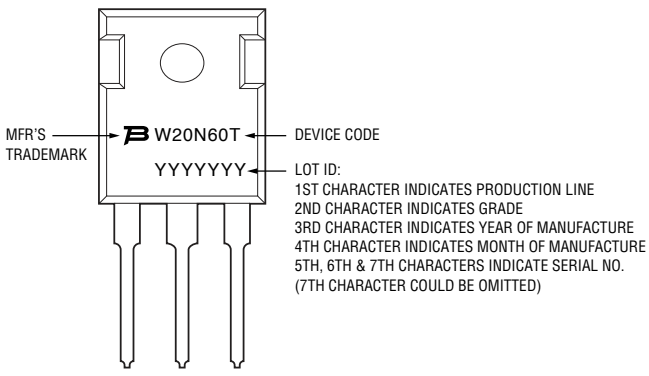
Maximum Electrical Ratings (T_C = 25 °C, unless otherwise specified)

Parameter	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CES}	600	V
Continuous Collector Current (T_C = 25 °C), limited by T_{jmax}	I_C	40	A
Continuous Collector Current (T_C = 100 °C), limited by T_{jmax}	I_C	20	A
Pulsed Collector Current, t_p limited by T_{jmax}	I_{CP}	60	A
Gate-Emitter Voltage	V_{GE}	±20	V
Continuous Forward Current (T_C = 25 °C), limited by T_{jmax}	I_F	40	A
Continuous Forward Current (T_C = 100 °C), limited by T_{jmax}	I_F	20	A
Short-circuit Withstand Time (V_{CE} = 300 V, V_{GE} = 15 V)	T_{SC}	10	μs
Total Power Dissipation	P_{total}	192	W
Storage Temperature	T_{STG}	-55 to +150	°C
Operating Junction Temperature	T_j	-55 to +150	°C

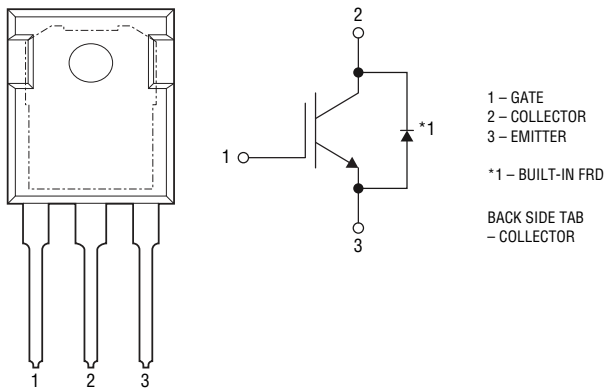
Thermal Resistance

Parameter	Symbol	Max	Unit
IGBT Thermal Resistance Junction - Case	$R_{th(j-c)_IGBT}$	0.65	°C/W
Diode Thermal Resistance Junction - Case	$R_{th(j-c)_Diode}$	1.19	°C/W

Typical Part Marking



Internal Circuit



WARNING Cancer and Reproductive Harm
www.P65Warnings.ca.gov

*RoHS Directive 2015/863, Mar 31, 2015 and Annex.
Specifications are subject to change without notice.
Users should verify actual device performance in their specific applications.
The products described herein and this document are subject to specific legal disclaimers as set forth on the last page of this document, and at www.bourns.com/docs/legal/disclaimer.pdf.

Static Electrical Characteristics (T_C = 25 °C, Unless Otherwise Specified)

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Collector-Emitter Breakdown Voltage	BV_{CES}	V_{GE} = 0 V, I_C = 250 µA	600	—	—	V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V_{GE} = 15 V, I_C = 20 A T_C= 25 °C	—	1.7	2.4	V
		V_{GE} = 15 V, I_C = 20 A T_C= 125 °C	—	1.9	—	
Diode Forward On-Voltage	V_F	I_F = 20 A, T_C = 25 °C	—	1.8	—	V
		I_F = 20 A, T_C = 125 °C	—	1.5	—	V
Gate Threshold Voltage	$V_{GE(th)}$	V_{CE} = V_{GE}, I_C = 250 µA	4.0	5.0	6.5	V
Collector Cut-off Current	I_{CES}	V_{GE} = 0 V, V_{CE} = 600 V	—	—	200	µA
Gate-Emitter Leakage Current	I_{GES}	V_{CE} = 0 V, V_{GE} = ±20 V	—	—	±400	nA

Dynamic Electrical Characteristics (T_C = 25 °C, Unless Otherwise Specified)

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Input Capacitance	C_{ies}	V_{CE} = 30 V, V_{GE} = 0 V, f = 1 MHz	—	1100	—	pF
Output Capacitance	C_{oes}		—	55	—	
Reverse Transfer Capacitance	C_{res}		—	22	—	
Total Gate Charge	Q_g	V_{CE} = 400 V, V_{GE} = 15 V I_C = 20.0 A	—	52	—	nC
Gate-Emitter Charge	Q_{ge}		—	15	—	
Gate-Collector Charge	Q_{gc}		—	22	—	

IGBT Switching Characteristics (Inductive Load, T_C = 25 °C, unless otherwise specified)

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Turn-on Delay Time	$t_{d(on)}$	V_{CE} = 400 V, V_{GE} = 15 V I_C = 20.0 A, R_G = 10 Ω	—	19	—	ns
Current Rise Time	t_r		—	55	—	ns
Turn-off Delay Time	$t_{d(off)}$		—	48	—	ns
Current Fall Time	t_f		—	115	—	ns
Turn-on Switching Energy	E_{on}		—	1	—	mJ
Turn-off Switching Energy	E_{off}		—	0.3	—	mJ
Total Switching Energy	E_{ts}		—	1.3	—	mJ

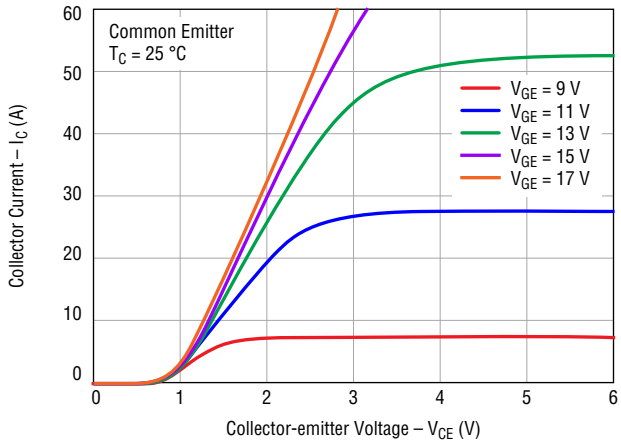
Specifications are subject to change without notice.
Users should verify actual device performance in their specific applications.
The products described herein and this document are subject to specific legal disclaimers as set forth on the last page of this document, and at www.bourns.com/docs/legal/disclaimer.pdf.

Diode Switching Characteristics (T_C = 25 °C, unless otherwise specified)

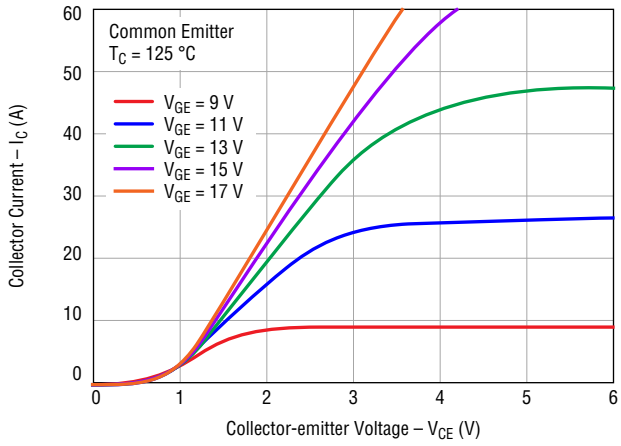
Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Reverse Recovery Time	t_{rr}	dI_F/dt = 200 A/μs I_F = 20.0 A	—	33.7	—	ns
Reverse Recovery Charge	Q_{rr}		—	73.3	—	nC

Electrical Characteristic Performance

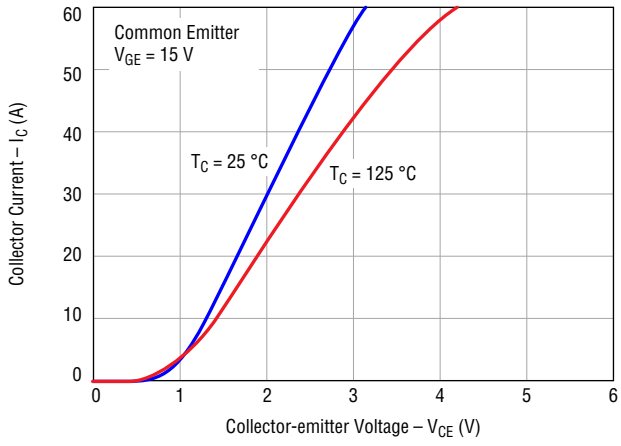
Typical Output Characteristics



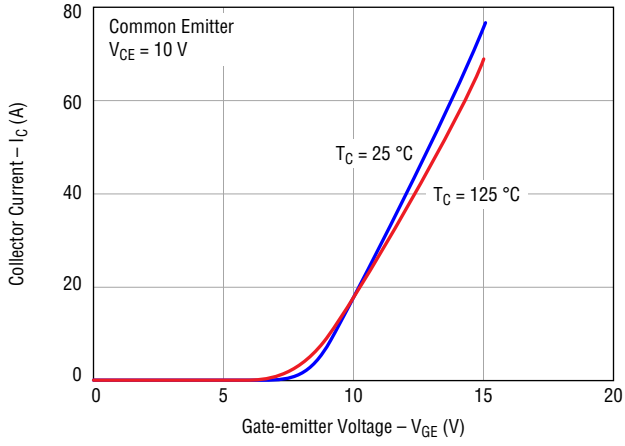
Typical Output Characteristics



Typical Saturation Voltage Characteristics



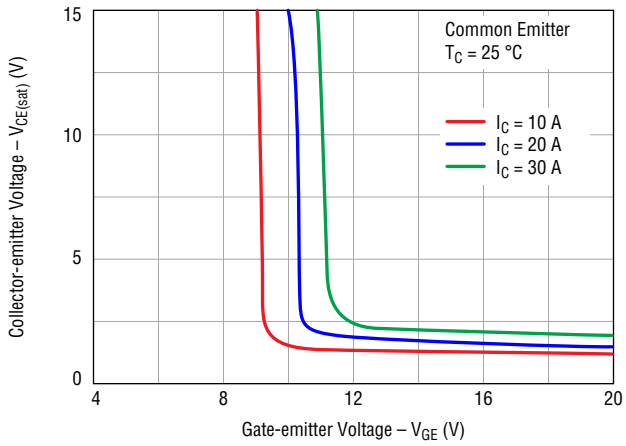
Typical Transfer Characteristics



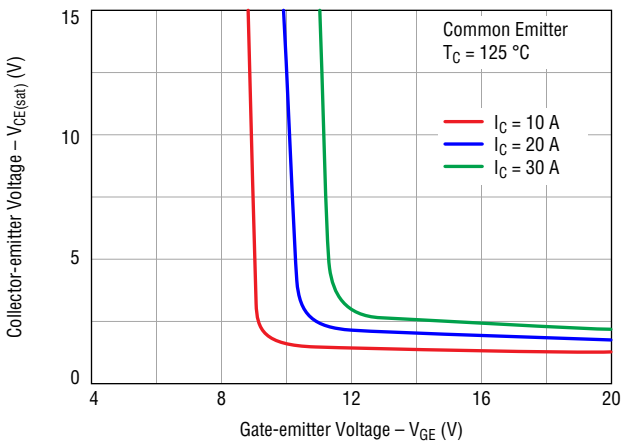
Specifications are subject to change without notice.
Users should verify actual device performance in their specific applications.
The products described herein and this document are subject to specific legal disclaimers as set forth on the last page of this document, and at www.bourns.com/docs/legal/disclaimer.pdf.

Electrical Characteristic Performance (continued)

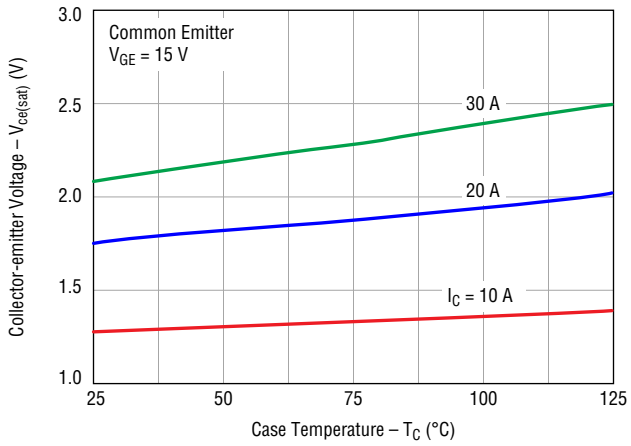
Typical $V_{CE(sat)}$ vs V_{GE} @ T_C = 25 °C



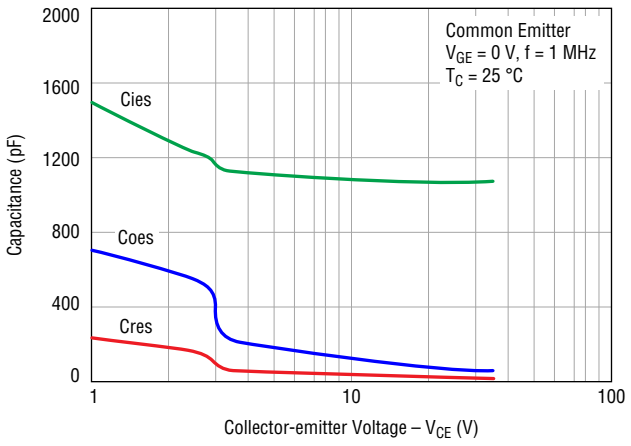
Typical $V_{CE(sat)}$ vs V_{GE} @ T_C = 125 °C



Typical $V_{CE(sat)}$ vs Case Temperature



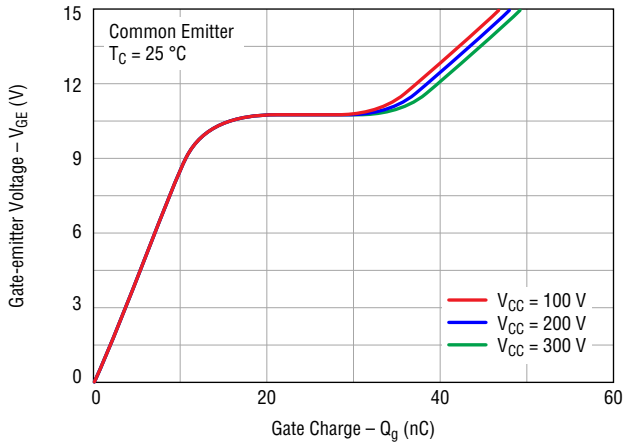
Typical Capacitance Characteristics



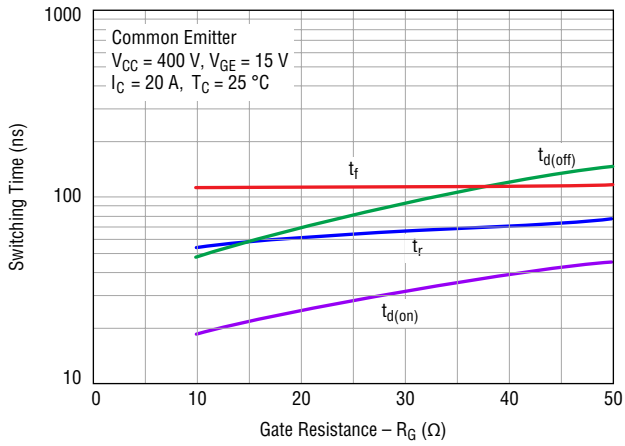
Specifications are subject to change without notice.
Users should verify actual device performance in their specific applications.
The products described herein and this document are subject to specific legal disclaimers as set forth on the last page of this document, and at www.bourns.com/docs/legal/disclaimer.pdf.

Electrical Characteristic Performance (continued)

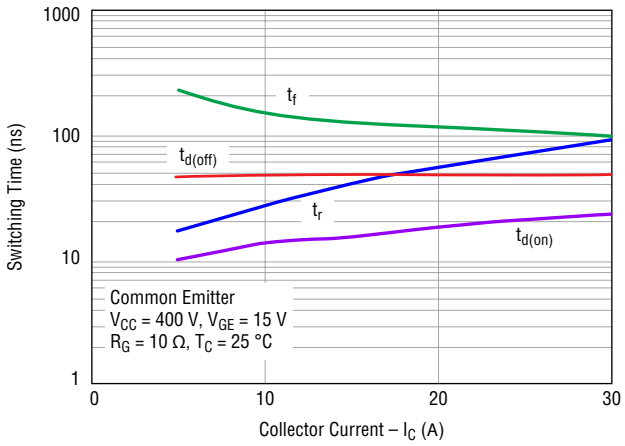
Typical Gate Charge Characteristics



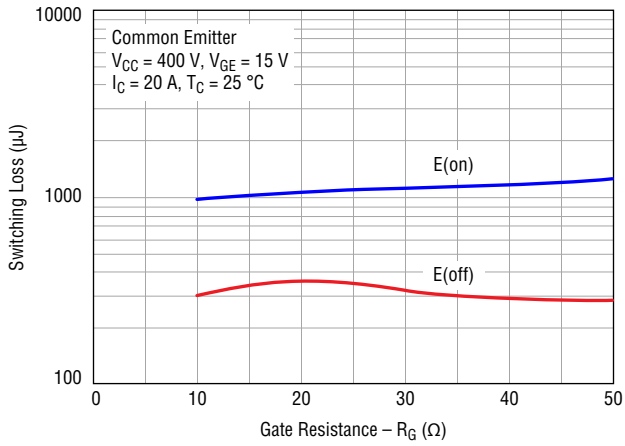
Typical Switching Time Characteristics vs R_G



Typical Switching Time Characteristics vs I_C



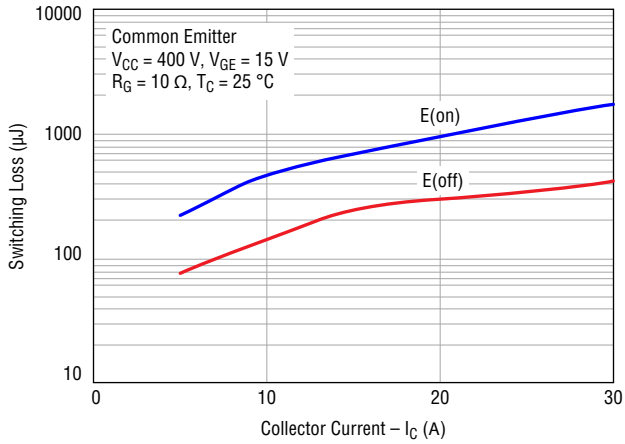
Typical Switching Loss vs R_G



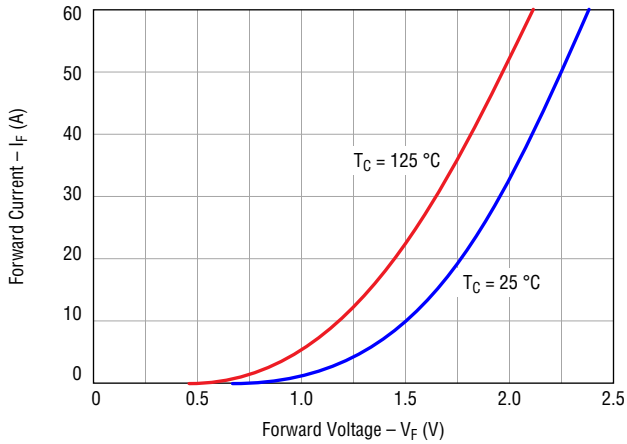
Specifications are subject to change without notice.
Users should verify actual device performance in their specific applications.
The products described herein and this document are subject to specific legal disclaimers as set forth on the last page of this document, and at www.bourns.com/docs/legal/disclaimer.pdf.

Electrical Characteristic Performance (continued)

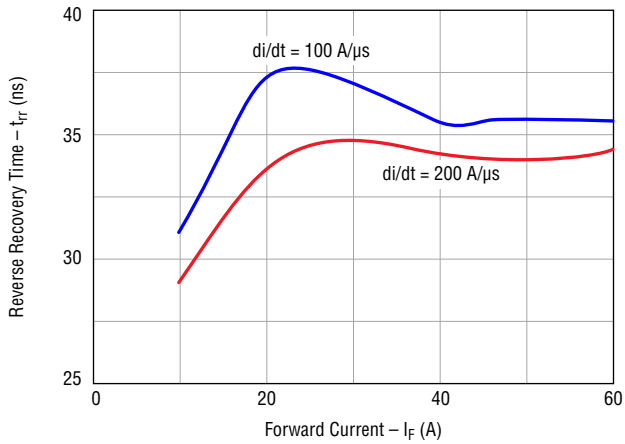
Typical Switching Loss Characteristics vs I_C



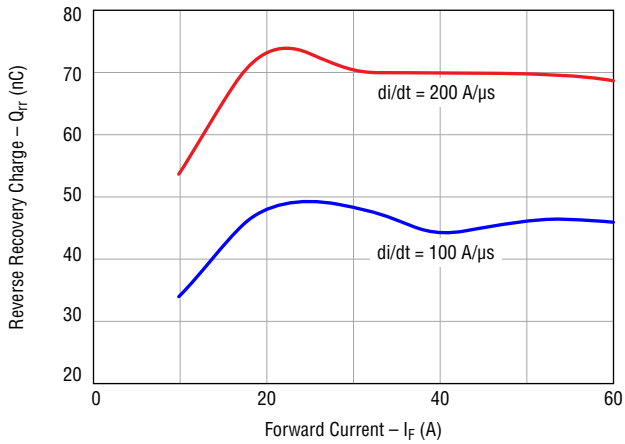
Typical Diode I_F vs V_F



Typical Reverse Recovery Time vs I_F



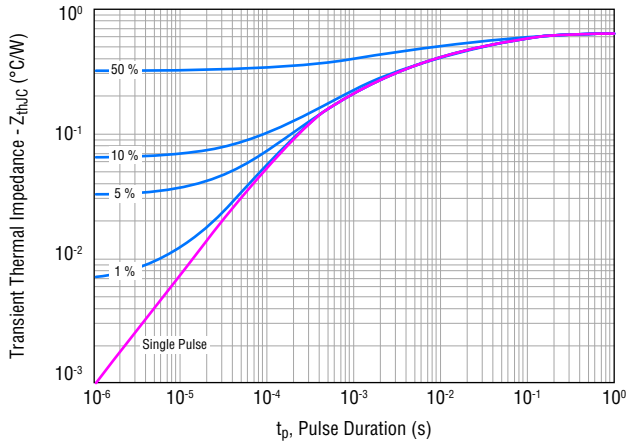
Typical Reverse Recovery Charge vs I_F



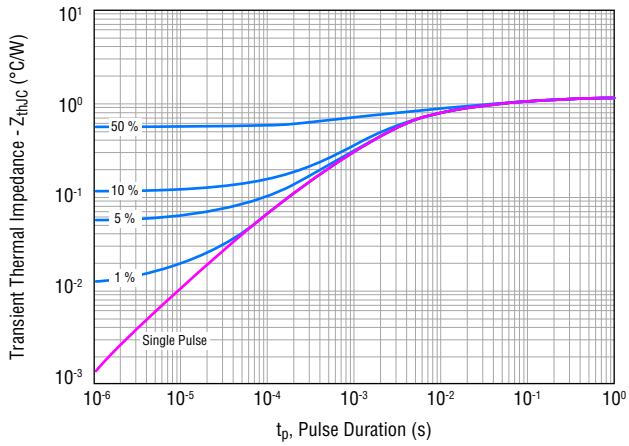
Specifications are subject to change without notice.
Users should verify actual device performance in their specific applications.
The products described herein and this document are subject to specific legal disclaimers as set forth on the last page of this document, and at www.bourns.com/docs/legal/disclaimer.pdf.

Electrical Characteristic Performance (continued)

IGBT Transient Thermal Impedance vs $t_{p(on)}$ Duration ($D=t_p/T$)



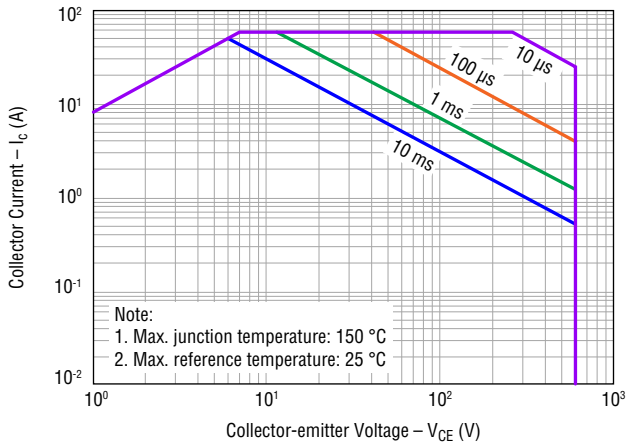
Diode Transient Thermal Impedance vs $t_{p(on)}$ Duration ($D=t_p/T$)



Specifications are subject to change without notice.
Users should verify actual device performance in their specific applications.
The products described herein and this document are subject to specific legal disclaimers as set forth on the last page of this document, and at www.bourns.com/docs/legal/disclaimer.pdf.

Electrical Characteristic Performance (continued)

Forward Bias Safe Operating Area

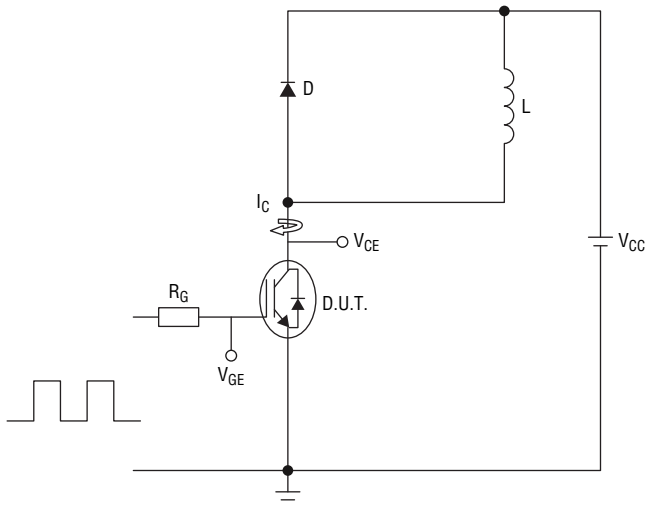


How to Order

B I D W 20 N 60 T

- B = Bourns®
- I = IGBT
- Type
  - D = Discrete
- Package Code
  - W = TO-247
- Current Rating
  - 20 = 20 A
- Device Type
  - N = N-channel
- Nominal Voltage (divided by 10)
  - 60 = 600 V
- Optimization
  - T = Medium Speed

Inductive Load Test Circuit



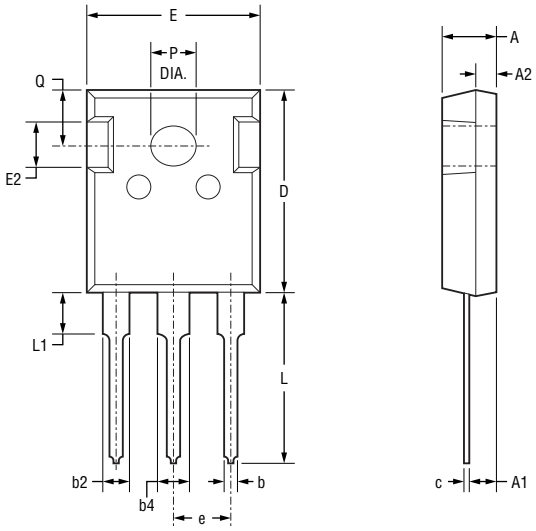
L = 2.8 mH, V_{CE} = 400 V, V_{GE} = 15 V, I_C = 20 A, R_G = 10 Ω

Environmental Characteristics

ESD Class (HBM) 1C

Specifications are subject to change without notice.
Users should verify actual device performance in their specific applications.
The products described herein and this document are subject to specific legal disclaimers as set forth on the last page of this document, and at www.bourns.com/docs/legal/disclaimer.pdf.

Product Dimensions



DIMENSIONS: MM / (INCHES)

Symbol	Min.	Nom.	Max.
A	4.80 (.189)	5.00 (.197)	5.20 (.205)
A1	2.21 (.087)	2.41 (.095)	2.59 (.102)
A2	1.85 (.073)	2.00 (.079)	2.15 (.085)
b	1.11 (.044)	—	1.36 (.054)
b2	1.91 (.075)	—	2.25 (.089)
b4	2.91 (.115)	—	3.25 (.128)
c	0.51 (.020)	—	0.75 (.030)
D	20.80 (.819)	21.00 (.827)	21.30 (.839)
E	15.50 (.610)	15.80 (.622)	16.10 (.634)
E2	4.40 (.173)	5.00 (.197)	5.20 (.205)
e		5.44 (.214) BSC	
L	19.72 (.776)	19.92 (.784)	20.22 (.796)
L1	—	—	4.30 (.169)
P	3.40 (.134)	—	3.80 (.150)
Q	5.60 (.220)	5.80 (.228)	6.00 (.236)

Packaging Specifications

BIDW20N60T ..... 30 pieces per tube

BOURNS®

Asia-Pacific: Tel: +886-2 2562-4117
Email: asiacus@bourns.com

EMEA: Tel: +36 88 885 877
Email: eurocus@bourns.com

The Americas: Tel: +1-951 781-5500
Email: americus@bourns.com

www.bourns.com

REV. 04/23

Specifications are subject to change without notice.
Users should verify actual device performance in their specific applications.
The products described herein and this document are subject to specific legal disclaimers as set forth on the last page of this document, and at www.bourns.com/docs/legal/disclaimer.pdf.

Legal Disclaimer Notice

BOURNS®

This legal disclaimer applies to purchasers and users of Bourns® products manufactured by or on behalf of Bourns, Inc. and its affiliates (collectively, "Bourns").

Unless otherwise expressly indicated in writing, Bourns® products and data sheets relating thereto are subject to change without notice. Users should check for and obtain the latest relevant information and verify that such information is current and complete before placing orders for Bourns® products.

The characteristics and parameters of a Bourns® product set forth in its data sheet are based on laboratory conditions, and statements regarding the suitability of products for certain "typical" applications are based on Bourns' knowledge of typical requirements in generic applications. Bourns assumes that "typical" applications include failsafe/backup features to address critical risks to users and are designed to allow rework of Bourns® product to avoid scrap of a device solely due to malfunctioning Bourns® product. The characteristics and parameters of a Bourns® product in a user application may vary from the data sheet characteristics and parameters due to (i) the combination of the Bourns® product with other components in the user's application, or (ii) the environment of the user application itself. The characteristics and parameters of a Bourns® product also can and do vary in different applications and actual performance may vary over time. Thus, users should always verify the actual performance of the Bourns® product in their specific devices and applications and make their own independent judgments regarding the suitability of Bourns® product and the amount of additional test margin to design into their device or application to compensate for differences between laboratory and real-world conditions.

Unless Bourns has explicitly designated an individual Bourns® product as meeting the requirements of a particular industry standard (e.g., IATF 16949) or a particular qualification (e.g., UL listed or recognized), Bourns is not responsible for any failure of an individual Bourns® product to meet the requirements of such industry standard or particular qualification even if such industry standard or qualification is a "state of art". Users of Bourns® products are responsible for ensuring compliance with safety-related requirements and standards applicable to their devices or applications.

Bourns® products are not recommended, authorized or intended for use in applications where failure or malfunction may result in personal injury, death, or severe property or environmental damage, such as without limitation nuclear, life-critical medical and certain automotive and aviation applications. Except as set forth in the bullet points below or unless expressly and specifically approved in writing on a case-by-case basis by an authorized Bourns' representative, use of any Bourns® products in such unauthorized high-risk applications is at the user's sole risk.

- Bourns considers implantable/invasive devices and devices/procedures designed as life-supporting or life-sustaining by the U.S. Food and Drug Administration or equivalent organizations outside of the United States as "life-critical" medical applications. Bourns expressly identifies those Bourns® standard products that are suitable for use in typical medical applications that are not life-critical in its publication entitled "Bourns Medical Grade Component Guide."

- Bourns expressly identifies those Bourns® standard products that are suitable for use in typical automotive applications associated with any Automate Safety Integrity Level (ASIL) in its publication entitled "Bourns Automotive Grade Component Guide." Bourns' designation of Bourns® product as compliant with the AEC-Q standard does not by itself mean that Bourns has approved such product for use in an automotive application.

- Bourns expressly identifies Bourns® standard products that are suitable for use in the typical aviation applications/systems requiring System Design Assurance Level (RTCA DO-254 DAL) of C, D or E in its publication entitled "Bourns Civilian Aerospace/Aviation Grade Component Guide." Bourns does not test its products for compliance with United States Federal Aviation Administration standards or any other generally equivalent governmental organization standard applicable to products designed or manufactured for use in aviation applications. Use of Bourns® standard components in aviation applications associated with RTCA DO-254 DAL A or B without proper approval noted above shall be at the user's sole risk.

- Bourns will review and authorize on a case-by-case basis the use of Bourns® standard products which are at least AEC-Q compliant in space-related civil applications (rockets, satellites) with a negotiated cross-waiver and indemnity agreement.

The use and level of testing applicable to Bourns® custom products shall be negotiated on a case-by-case basis by Bourns and the user for which such Bourns® custom products are specially designed. Absent a written agreement between Bourns and the user regarding the use and level of such testing, the above provisions applicable to Bourns® standard products shall also apply to such Bourns® custom products.

Use of Bourns® products or Bourns' technology in military/defense applications must be reviewed with Bourns for compliance with applicable export control laws and embargoes. Users shall not sell, transfer, export or re-export (which includes transfers within a country) any Bourns® products or technology or technical data for use in activities which involve the design, development, production, use or stockpiling of nuclear, chemical or biological weapons or missiles, nor shall they use Bourns® products or technology or technical data in any facility which engages in activities relating to such devices. Further, Bourns® products and Bourns' technology and technical data may not under any circumstance be exported or re-exported to countries subject to international sanctions or embargoes. Bourns® products and technology may not, without prior authorization from Bourns and/or the Government of a country where such product/technology is designed and/or manufactured, be resold, transferred, or re-exported (including within the same country) to any party not eligible to receive commodities, software, and technical data originating in such country.

To the maximum extent permitted by applicable law, Bourns disclaims (i) any and all liability for special, punitive, consequential, incidental or indirect damages or lost revenues or lost profits, and (ii) any and all implied warranties (those not based on parameters specified in Bourns' data sheets and/or specifications), including implied warranties of fitness for particular purpose, non-infringement and merchantability.

For your convenience, copies of this Legal Disclaimer Notice with German, Spanish, Japanese, Traditional Chinese and Simplified Chinese bilingual versions are available at:

Web Page: https://www.bourns.com/legal/disclaimers-terms-and-policies
PDF: https://www.bourns.com/docs/Legal/disclaimer.pdf

ENTEGRECİ

Bu belge www.entegreci.com üzerinden sunulmaktadır.

Elektronik komponent tedarikinde Entegreci

Entegreci, Eskişehir merkezli, Türkiye geneline satış yapan bir elektronik komponent mağazasıdır. Entegreler (IC), mikrodenetleyiciler, transistörler, diyotlar, pasif elemanlar, konnektörler, modüller ve geliştirme kartları tek adetten seri üretim adetlerine kadar satılır. Ürün sayfalarında güncel stok durumunu, fiyatı ve datasheet bağlantısını bulabilirsiniz.

Parça koduyla arama

Üretici parça numarasını yazın; stok ve fiyatı hemen görün.

www.entegreci.com

Ürün kategorileri

Entegreden kapasitöre tüm elektronik komponent kategorileri.

Kategorilere göz atın

Üreticiler

Aradığınız üreticinin ürünlerini tek sayfada inceleyin.

Üreticileri görün

Toplu alım ve teklif

Listede olmayan ya da yüksek adetli parçalar için teklif isteyin.

Teklif isteyin

www.entegreci.com | **destek@entegreci.com** | **0850 305 90 34**

Entegreci is an online electronic components store based in Türkiye. Search by manufacturer part number to see stock, prices and datasheets for integrated circuits, microcontrollers, transistors, passive components and connectors, or request a quote for parts that are not listed.

Bu sayfa Entegreci tarafından eklenmiştir. Belgenin önceki sayfaları asıl yayıncısına aittir ve içeriği değiştirilmemiştir; en güncel sürüm için belgenin yayıncısına başvurun.